

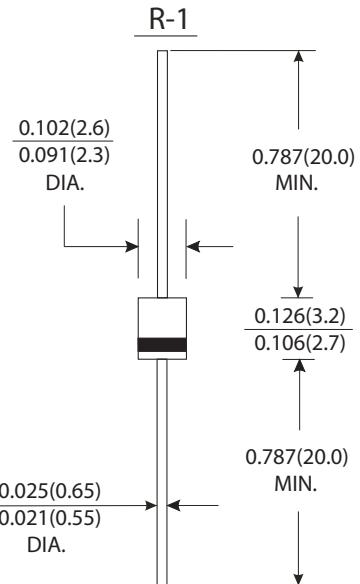
# DEC

1S20 THRU 1S100

CURRENT 1.0Ampere  
VOLTAGE 20 to 40 Volts

## Features

- Plastic Package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, Low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications



Dimensions in inches and (millimeters)

## Mechanical Data

- Case : R-1 molded plastic body
- Terminals : Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Weight : 0.007 ounce, 0.20 gram

## Maximum Ratings and Electrical Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified, single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%)

	Symbols	1S20	1S30	1S40	1S50	1S60	1S80	1S100	Units			
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	20	30	40	50	60	80	100	Volts			
Maximum RMS voltage	V <sub>RMS</sub>	14	21	28	35	42	57	71	Volts			
Maximum DC blocking voltage	V <sub>DC</sub>	20	30	40	50	60	80	100	Volts			
Maximum average forward rectified current 0.375"(9.5mm) lead length at T <sub>L</sub> =90 °C	I <sub>(AV)</sub>	1.0						Amp				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method) at T <sub>L</sub> =70 °C	I <sub>FSM</sub>	40.0						Amps				
Maximum instantaneous forward voltage at 1.0A (Note 1)	V <sub>F</sub>	0.55		0.70		0.75	0.83	Volts				
Maximum instantaneous reverse current at rated DC blocking voltage (Note1)	T <sub>A</sub> =25 °C	I <sub>R</sub>	0.5						mA			
	T <sub>A</sub> =100 °C		10									
Typical junction capacitance (Note 3)	C <sub>J</sub>	110						PF				
Typical thermal resistance (Note 2)	R <sub>θJA</sub>	50						°C/W				
Operating junction temperature range	T <sub>J</sub>	-65 to +125			-65 to +150			°C				
Storage temperature range	T <sub>STG</sub>	-65 to +150						°C				

### Notes:

- (1) Pulse test: 300µS pulse width, 1% duty cycle
- (2) Thermal resistance from junction to ambient P.C.B. mounted, 0.5"(12.7mm) lead length
- (3) Measured 1.0MHz and reverse voltage of 4.0 volts

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## RATINGS AND CHARACTERISTIC CURVES 1S20 THRU 1S100

FIG.1-FORWARD CURRENT DERATING CURVE

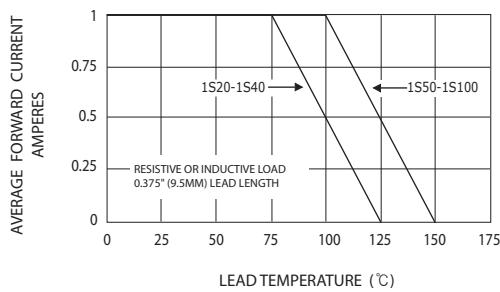


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

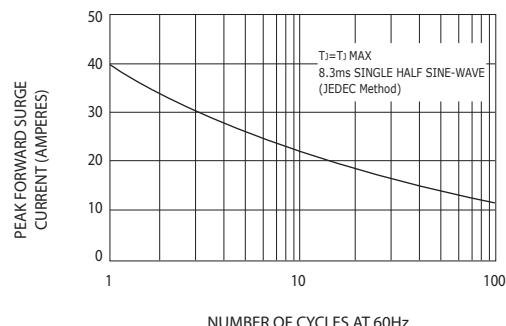


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

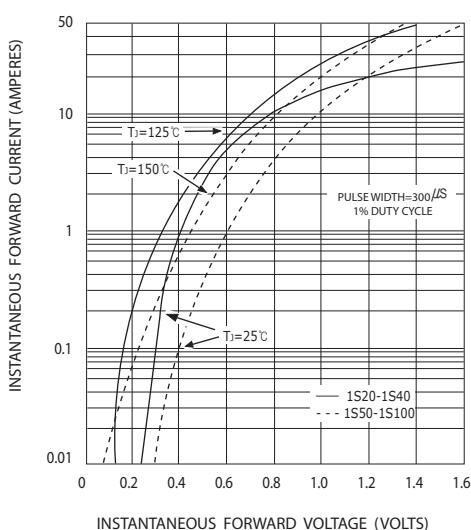


FIG.4-TYPICAL REVERSE CHARACTERISTICS

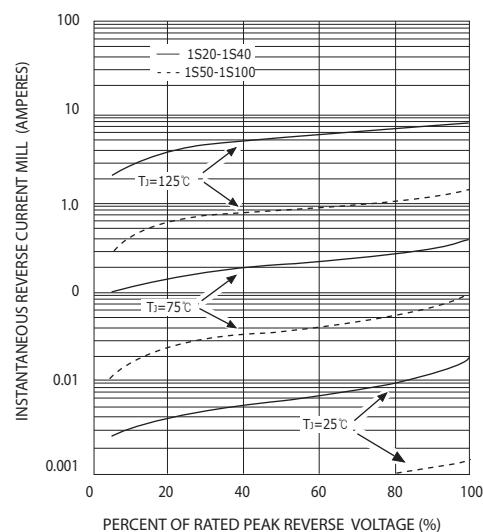


FIG.5-TYPICAL JUNCTION CAPACITANCE

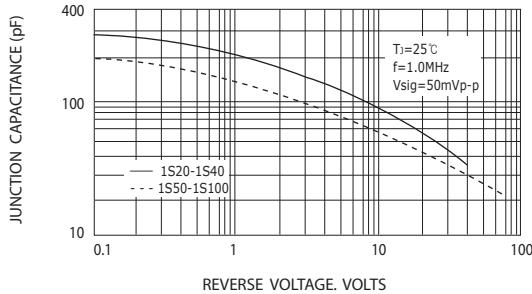


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

